

SURFACE MOUNT RECTIFIERS

VOLTAGE RANGE: 500 --- 600 V
CURRENT: 3.0 A

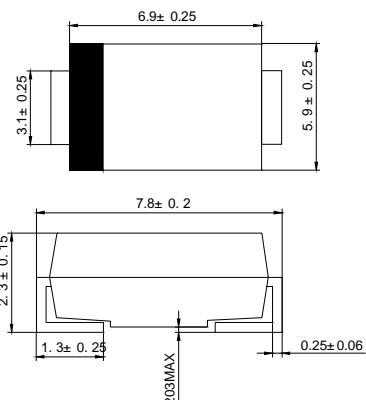
FEATURES

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol,Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-214AB(SMC), molded plastic
- ◇ Terminals: Solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.007 ounces, 0.21 grams
- ◇ Mounting position: Any

SMC



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

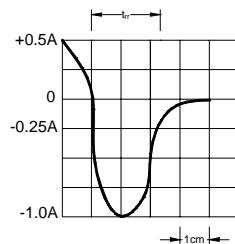
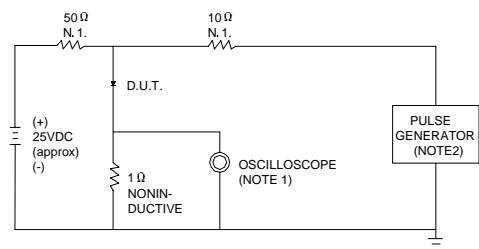
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ES3H	ES3J	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	500	600	V
Maximum RMS voltage	V _{RMS}	350	420	V
Maximum DC blocking voltage	V _{DC}	500	600	V
Maximum average forward rectified current @T _A =100°C	I _{F(AV)}	3.0		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	100		A
Maximum instantaneous forward voltage at 3.0 A	V _F	1.70		V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =125°C	I _R	10 500		µA
Typical reverse recovery time (Note1)	t _{rr}	35		ns
Typical junction capacitance (Note2)	C _J	45		pF
Typical thermal resistance (Note3)	R _{θJA}	25		°C/W
Operating junction temperature range	T _J	-55 ---- +150		°C
Storage temperature range	T _{STG}	-55 ---- +150		°C

NOTE: 1. Measured with I_F=0.5A, I_R=1A, I_{rr}=0.25A.www.diode.kr

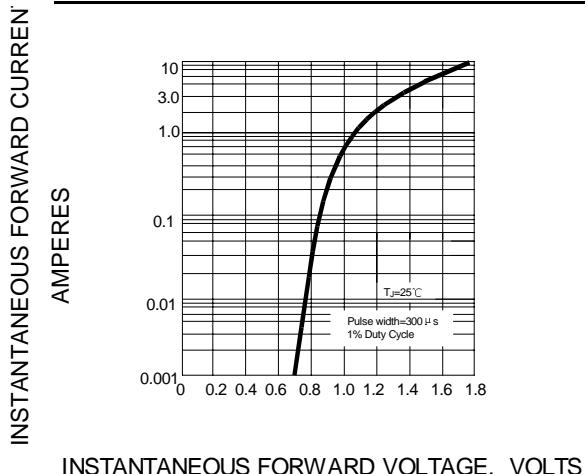
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient and junction to lead P.C.B. mounted on 0.27"X0.27"(7.0X7.0mm²) copper pad areas

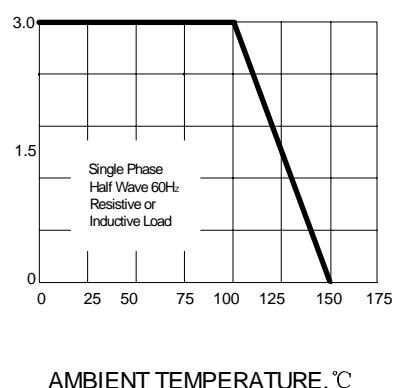
FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

NOTES:
1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ.22pF.
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω.

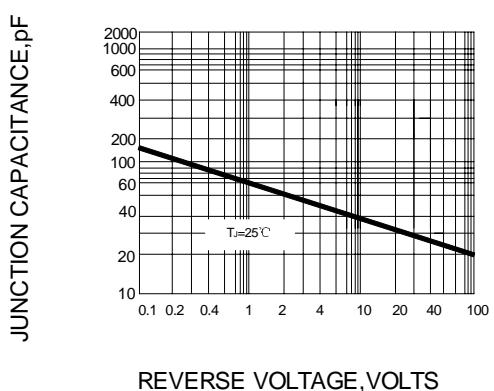
SET TIME BASE FOR 20/30 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

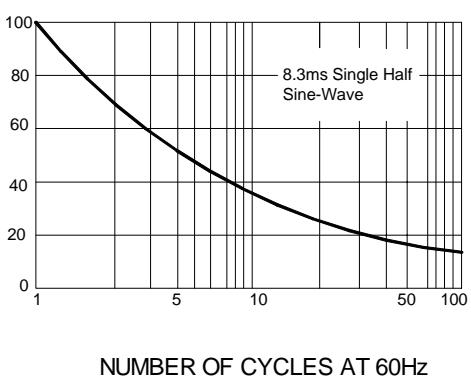
INSTANTANEOUS FORWARD CURRENT
AMPERES

FIG.3 -- FORWARD DERATING CURVE

AMBIENT TEMPERATURE, $^\circ\text{C}$

FIG.4 -- TYPICAL JUNCTION CAPACITANCE

JUNCTION CAPACITANCE,pF
REVERSE VOLTAGE, VOLTS

FIG.5 -- PEAK FORWARD SURGE CURRENT

PEAK FORWARD SURGE CURRENT
AMPERES